## Self-Biased BFP405

- SIEGET ${ }^{\circledR} 25$ - Technology
- Small SCT598-Package
- Control Pin For Switching The Device Off
- Current Easy Adjustable By An External Resistor
- Voltage Independent Current ( $2 \mathrm{~V}-4.5 \mathrm{~V}$ )


ESD: Electrostatic discharge sensitive device, observe handling precautions!

| Type | Marking | Ordering Code <br> (8-mm taped) | Pin Configuration <br> (circuit Diagram) | Package |
| :--- | :---: | :---: | :---: | :---: |
| BGC405 | 40s | Q62702-G0091 | see below | SCT598 |

Equivalent Circuit


Pin Connections, SCT598


Note: Top View

## Description

The BGC405 is a silicon self biased RF Transistor (Q1). It offers an adjustable collector current nearly independent from device voltage in the range from 2.0 V to 4.5 V . Additionally a control pin (Vc) for switching the device off is provided. The collector current can be adjusted by connecting a resistor (Rx) between Vcc and Vr.

## Maximum Ratings

| Parameter | Symbol |  | Unit |
| :--- | :--- | :---: | :--- |
| Device current | $I_{C C}$ | 12 | mA |
| Device voltage | $V_{c C}$ | 4.5 | V |
| Total power dissipation, $\mathrm{Ts}_{\mathrm{s}} \leq 120^{\circ} \mathrm{C}{ }^{1)}$ | $P_{\text {tot }}$ | 54 | mW |
| Control voltage | $V c$ | $\mathrm{VcC}+0.5$ | V |
| Input Current for pin 1 | Ir | 380 | $\mu \mathrm{~A}$ |
|  |  |  |  |
| Junction temperature | $T_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Ambient temperature range | $T_{\mathrm{A}}$ | $-65 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range | $T_{\text {stg }}$ | $-65 \ldots+150$ | ${ }^{\circ} \mathrm{C}$ |

Thermal Resistance

| Junction-soldering point | $1)$ | $R_{\text {th }}$ JS | $\leq 530$ | K/W |
| :--- | :--- | :--- | :--- | :--- |

1) $T_{S}$ is measured on the Ground lead at the soldering point to the pcb.

Electrical Specifications (Measured in Test Fixture applying the circuit specified in Figure 1 with $\mathrm{Rx}=82 \Omega$ ), $\mathrm{Tc}=25^{\circ} \mathrm{C}, \mathrm{Vcc}=3 \mathrm{~V}, \mathrm{I}_{\mathrm{cc}} \approx 7 \mathrm{~mA}$ unless noted

| Symbol | Parameter |  | Unit | Min | Typ | Max |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Gp | Power Gain ( $\left\|\mathrm{S}_{21}\right\|^{2}$ ) | $\mathrm{f}=900 \mathrm{MHz}$ | dB | 19.5 | 21 |  |
|  |  | $\mathrm{f}=1.8 \mathrm{GHz}$ |  | 16.5 | 18 |  |
| NF | Noise Figure (in $50 \Omega$ System) | $f=900 \mathrm{MHz}$ | dB |  | 1.8 | 2.1 |
|  |  | $\mathrm{f}=1.8 \mathrm{GHz}$ |  |  | 2.0 | 2.3 |
| $\mathrm{P}_{-1 \mathrm{~dB}}$ | Output Power at 1dB Gain Compression (in $50 \Omega$ System) | $\mathrm{f}=900 \mathrm{MHz}$ | dBm |  | 1 |  |
|  |  | $\mathrm{f}=1.8 \mathrm{GHz}$ |  |  | 0.5 |  |
| $\mathrm{IP}_{3}$ | Third Order Intercept Point | $f=900 \mathrm{MHz}$ | dBm |  | 15 |  |
|  | (Output, Гopt) | $\mathrm{f}=1.8 \mathrm{GHz}$ |  |  | 15 |  |
| $R L_{\text {in }}$ | Input Return Loss | $\mathrm{f}=900 \mathrm{MHz}$ | dB |  | 5 |  |
|  |  | $\mathrm{f}=1.8 \mathrm{GHz}$ |  |  | 8 |  |
| $\mathrm{RL}_{\text {out }}$ | Output Return Loss | $\mathrm{f}=900 \mathrm{MHz}$ | dB |  | 1.5 |  |
|  |  | $\mathrm{f}=1.8 \mathrm{GHz}$ |  |  | 3 |  |
| $\mathrm{t}_{\text {on }}$ | On Switching Time ${ }^{\text {3) }}$ |  | $\mu \mathrm{S}$ |  | 3.7 |  |
| $\mathrm{t}_{\text {off }}$ | Off Switching Time ${ }^{\text {3) }}$ |  | $\mu \mathrm{s}$ |  | 2.5 |  |
| $l_{\text {leak }}$ | Leakage Current In Sleep Mode |  | $\mu \mathrm{A}$ |  | <10 |  |
| $\mathrm{I}_{\mathrm{c} \text { con }}$ | Controll Pin (Vc) Current in Active Mode ${ }^{2 /}$ |  | $\mu \mathrm{A}$ |  | 35 |  |
| $\mathrm{I}_{\mathrm{VcOHf}}$ | Controll Pin (Vc) Current in Sleep Mode ${ }^{2 /}$ |  | nA |  | -60 |  |
| $\mathrm{V}_{\text {cmin }}$ | Minimum Voltage at Vc for Sleep Mode |  | V |  | $\mathrm{V}_{\text {cc }}-0.3 \mathrm{~V}$ |  |
| $\mathrm{V}_{\text {cmax }}$ | Maximum Voltage at Vc for Active Mode |  | V |  | $0 \mathrm{~V}+0.3 \mathrm{~V}$ |  |

[^0]
## Power Gain

## versus Frequency

Vcc=3V, Icc=5mA

$|\mathbf{S 2 1}|^{2}$
versus Frequency and Temperature
Vcc=3V, Icc=7mA


Device Current
versus Device Voltage


Device Current
versus Voltage at Vc
Vcc=3V; Rx=82 $\Omega$


## Device Current

versus Rx and Temperature
Vcc=3V


## Typical Application



Figure 1. Typical Application and Internal Circuit

## Remarks:

1) To provide low frequency stability C 2 should be 10 times C 3 .
2) Be aware that also coupling capacitors determine the switching times.
3) The collector current at Q1 can be estimated by Ic=0.6V / Rx[ $\Omega$ ].
4) Place C 2 as close to the device as possible.

## Layout Proposal



Figure 2. Layout Proposal

Part List for Vcc=3V, $I_{c c} \approx 7 \mathrm{~mA}$

| Component | Value | Comment |
| :--- | :--- | :--- |
| L1 | 100 nH | RFC |
| C2 | 1 nF | Compensation Capacitor for Low Frequency Stabilization |
| C3 | 100 pF | RFC |
| C4 | 150 pF | Blocking Capacitor |
| C5 | 100 nF | Blocking Capacitor |
| C6 | 220 pF | Coupling Capacitor |
| C7 | 220 pF | Coupling Capacitor |
| Rx | $82 \Omega$ | Current Adjust |
| Substrate | $\mathrm{h}=0.5 \mathrm{~mm}$ | Fr4, $\varepsilon_{\mathrm{r}}=4.5$ |
| BGC405 |  |  |

This proposal demonstrates how to use the BGC405 as a Self-Biased Transistor. As for a discrete Transistor matching circuits have to be applied. A good starting point for various applications are the Application Notes provided for the BFP405.

## SPICE Model

The following SPICE Listing describes the circuit shown in figure 3. It is valid for low frequencies. For frequencies above 100 MHz the parasitic circuit elements noted in figure 4 and table 1 should be added.


Figure. 3: Circuit used in the SPICE File

* Preliminary SPICE Model for BGC405
* SIEMENS HIGH FREQUENCY PRODUCTS
* Small Scale MMIC Design Group
. PARAM R=82
** Analysis setup **
*.TRAN 2ns 15u 0 2n
. TEMP $+27-40+85$
. DC LIN V1 0V 4V 0.1V
*.DC LIN V2 OV 3V 0.1V
*.STEP PARAM R LIST 334768100150
* Voltage supply

V1 Vcc 0 DC 3.0V
V2 Vc 0 DC 0.0V
*Vpul Vc $0 \quad$ PULSE (0 3V 100ns 0 9us 1000m)

| * | Internal | Resistors |  |
| :--- | ---: | ---: | :--- |
| R1 | 3 VC | 47 k | TC=-0.0006,0.0000025 |
| R2 | Vr 2 | 500 | TC=-0.0006,0.0 |
| R3 | Vb | 0 | 10 k |
| R4 | Vb rfin | 2.7 k | TC $=-0.0006,0.0000025$ |
|  |  |  |  |

* External Resistors

| Rx | Vcc Vr | $\{R\}$ | $\mathrm{TC}=+0.000050,0.0$ |
| :--- | :--- | :--- | :--- |
| Rout | vout 0 | 50 |  |
| Rin | vin 0 | 50 |  |

* External Capacitors

| C 2 | Vb 0 | 1 nF |
| :--- | :--- | :--- |
| C | Vr 0 | 100 pF |
| C7 | rfin vin | 220 pF |
| C6 | rfout vout | 220 pF |

* Inductors (external)

L1 Vr rfout 100 nH

| * Transistors |  |  |  |
| :--- | :--- | :--- | :--- |
| Q1 | rfout rfin 0 | BFP405 |  |
| X2 | 2 | 3 | Vb 0 |

.PROBE
.MODEL BFP405 NPN(

+ IS $=1.9969 \mathrm{e}-16$
$+\mathrm{VAF}=39.251$
$+\mathrm{NE}=1.7763$
$+\mathrm{VAR}=34.368$
$+\mathrm{NC}=1.3152$
+ RBM $=1.3491$
$+\mathrm{CJE}=3.7265 \mathrm{e}-15$
$+\mathrm{TF}=4.5899 \mathrm{e}-12$
$+\mathrm{ITF}=0.0013364$
$+\mathrm{VJC}=0.99532$
$+\mathrm{TR}=1.4935 \mathrm{e}-09$
$+\mathrm{MJS}=0$
$+\mathrm{XTI}=3$
$\mathrm{NF}=1.0405$
ISE $=1.5761 \mathrm{e}-14$
NR $=0.96647$
ISC $=3.7223 \mathrm{e}-17$
$I R B=0.00021215$
$\mathrm{RC}=0.12691$
$\mathrm{MJE}=0.37747$
$\mathrm{VTF}=0.19762$
CJC $=9.6941 \mathrm{e}-14$
$\mathrm{XCJC}=0.08161$
VJS $=0.75$
$\mathrm{EG}=1.11$

| SUBCKT |  |  |  |  |  |  |  |
| :--- | :--- | ---: | :--- | :--- | :--- | :--- | :--- |
| Q1 | 8PL18 | 3 | 2 | 1 | 94 |  |  |
| Q1 | 993 | 2 | 3 | 94 | TL18 | 8 |  |
| Q2 | 94 | 2 | 3 | 94 | VSL18 | 8 |  |
| Q3 | 94 | 2 | 993 | 94 | LSL18 | 8 |  |
| RCEX | 993 | 1 |  |  | 0.204 |  |  |

.ENDS

| Q1 | 993 | 2 | 3 | 94 | TL18 | 2 |
| :--- | :--- | :--- | :--- | :--- | ---: | :--- |
| Q2 | 94 | 2 | 3 | 94 | VSL18 | 2 |
| Q3 | 94 | 2 | 993 | 94 | LSL18 | 2 |
| RCEX | 993 | 1 |  |  | 0.816 |  |

.ENDS

| . MODEL | TL18 | PNP |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| +IS | $=2.914 \mathrm{E}-17$ | NF | $=1.000 \mathrm{E}+00$ | BF | $=4.005 \mathrm{E}+02$ |
| +NE | $=1.553 \mathrm{E}+00$ | ISE | $=6.923 \mathrm{E}-16$ | NR | $=1.000 \mathrm{E}+00$ |
| +BR | $=2.869 \mathrm{E}+01$ | NC | $=1.500 \mathrm{E}+00$ | ISC | $=8.190 \mathrm{E}-15$ |
| +VAF | $=6.000 \mathrm{E}+01$ | IKF | $=1.676 \mathrm{E}-04$ | VAR | $=2.214 \mathrm{E}+00$ |
| +IKR | $=2.474 \mathrm{E}-05$ | RB | $=6.000 \mathrm{E}+01$ | IRB | $=0.000 \mathrm{E}+00$ |
| +RBM | $=4.000 \mathrm{E}+01$ | RE | $=2.597 \mathrm{E}+00$ | RC | $=4.000 \mathrm{E}+00$ |
| +XTB | $=-6.000 \mathrm{E}-01$ | EG | $=1.156 \mathrm{E}+00$ | XTI | $=3.000 \mathrm{E}+00$ |
| +CJE | $=1.200 \mathrm{E}-14$ | VJE | $=4.900 \mathrm{E}-01$ | MJE | $=1.360 \mathrm{E}-01$ |
| +TF | $=7.600 \mathrm{E}-10$ | XTF | $=2.872 \mathrm{E}-01$ | VTF | $=1.000 \mathrm{E}+03$ |
| +ITF | $=1.400 \mathrm{E}-02$ | CJC | $=4.700 \mathrm{E}-13$ | VJC | $=7.610 \mathrm{E}-01$ |
| +MJC | $=3.760 \mathrm{E}-01$ | XCJC | $=1.000 \mathrm{E}+00$ | TR | $=0.000 \mathrm{E}+00$ |
| +CJS | $=0.000 \mathrm{E}+00$ | VJS | $=7.500 \mathrm{E}-01$ | MJS | $=0.000 \mathrm{E}+00$ |
| +PTF | $=0.000 \mathrm{E}+00$ | FC | $=5.000 \mathrm{E}-01$ |  |  |


| .MODEL |  |
| :--- | :--- |
| VSL18 |  |
| +IS | $=$ |
| +NE | $=1.630 \mathrm{E}-19$ |
| +BR | $=1.000 \mathrm{E}+00$ |
| +VAF | $=1.000 \mathrm{E}+02$ |
| +IKR | $=1.000 \mathrm{E}+00$ |
| +RBM | $=0.000 \mathrm{E}+00$ |
| +XTB | $=0.000 \mathrm{E}+00$ |
| +CJE | $=0.000 \mathrm{E}+00$ |
| +TF | $=2.000 \mathrm{E}-09$ |
| +ITF | $=1.000 \mathrm{E}+06$ |
| +MJC | $=3.770 \mathrm{E}-01$ |
| +CJS | $=0.000 \mathrm{E}+00$ |
| +PTF | $=0.000 \mathrm{E}+00$ |


| PNP | $=1.000 \mathrm{E}+00$ | BF | $=1.000 \mathrm{E}+09$ |
| :--- | :--- | :--- | :--- |
| NF | $=1.000 \mathrm{E}+00$ | NR | $=1.000 \mathrm{E}+00$ |
| ISE | $=0.00$ |  |  |
| NC | $=2.000 \mathrm{E}+00$ | ISC | $=0.000 \mathrm{E}+00$ |
| IKF | $=1.794 \mathrm{E}-04$ | VAR | $=1.700 \mathrm{E}+00$ |
| RB | $=0.000 \mathrm{E}+00$ | IRB | $=0.000 \mathrm{E}+00$ |
| RE | $=0.000 \mathrm{E}+00$ | RC | $=0.000 \mathrm{E}+00$ |
| EG | $=1.122 \mathrm{E}+00$ | XTI | $=3.000 \mathrm{E}+00$ |
| VJE | $=6.800 \mathrm{E}-01$ | MJE | $=3.400 \mathrm{E}-01$ |
| XTF | $=0.000 \mathrm{E}+00$ | VTF | $=1.000 \mathrm{E}+03$ |
| CJC | $=1.950 \mathrm{E}-13$ | VJC | $=5.500 \mathrm{E}-01$ |
| XCJC | $=0.000 \mathrm{E}+00$ | TR | $=0.000 \mathrm{E}+00$ |
| VJS | $=7.500 \mathrm{E}-01$ | MJS | $=0.000 \mathrm{E}+00$ |
| FC | $=5.000 \mathrm{E}-01$ |  |  |


| . MODEL | LSL18 | PNP |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
| +IS | $=4.261 \mathrm{E}-17$ | NF | $=1.000 \mathrm{E}+00$ | BF | $=1.000 \mathrm{E}+09$ |
| +NE | $=1.500 \mathrm{E}+00$ | ISE | $=0.000 \mathrm{E}+00$ | NR | $=1.000 \mathrm{E}+00$ |
| +BR | $=1.000 \mathrm{E}+09$ | NC | $=2.000 \mathrm{E}+00$ | ISC | $=0.000 \mathrm{E}+00$ |
| +VAF | $=6.000 \mathrm{E}+01$ | IKF | $=9.648 \mathrm{E}-05$ | VAR | $=1.700 \mathrm{E}+00$ |
| +IKR | $=1.000 \mathrm{E}+00$ | RB | $=0.000 \mathrm{E}+00$ | IRB | $=0.000 \mathrm{E}+00$ |
| +RBM | $=0.000 \mathrm{E}+00$ | RE | $=0.000 \mathrm{E}+00$ | RC | $=0.000 \mathrm{E}+00$ |
| +XTB | $=0.000 \mathrm{E}+00$ | EG | $=1.158 \mathrm{E}+00$ | XTI | $=3.000 \mathrm{E}+00$ |
| +CJE | $=0.000 \mathrm{E}+00$ | VJE | $=6.800 \mathrm{E}-01$ | MJE | $=3.400 \mathrm{E}-01$ |
| +TF | $=1.000 \mathrm{E}-09$ | XTF | $=0.000 \mathrm{E}+00$ | VTF | $=1.000 \mathrm{E}+03$ |
| +ITF | $=1.000 \mathrm{E}+06$ | CJC | $=0.000 \mathrm{E}+00$ | VJC | $=4.600 \mathrm{E}-01$ |
| +MJC | $=3.000 \mathrm{E}-01$ | XCJC | $=0.000 \mathrm{E}+00$ | TR | $=0.000 \mathrm{E}+00$ |
| +CJS | $=0.000 \mathrm{E}+00$ | VJS | $=7.500 \mathrm{E}-01$ | MJS | $=0.000 \mathrm{E}+00$ |
| +PTF | $=0.000 \mathrm{E}+00$ | FC | $=5.000 \mathrm{E}-01$ |  |  |

.END


Figure 4. Parasitic circuit elements for frequencies above 100 MHz

| Element | Value |
| :---: | :---: |
| Lp1 | 0.58 nH |
| Lp2 | 0.56 nH |
| Lp3 | 0.23 nH |
| Lp4 | 0.05 nH |
| Lp5 | 0.53 nH |
| Lp6 | 0.47 nH |
| Lp7 | 1 nH |
| Cp1 | 134 fF |
| Cp2 | 136 fF |
| Cp3 | 6.9 fF |

Table 1. Parasitic circuit elements for frequencies above 100 MHz

## Package



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[^0]:    ${ }^{2)}$ A positive sign denotes a current flowing form the Pin to the external circuit.
    ${ }^{3)}$ This values are valid for $\mathrm{C} 2=1 \mathrm{nF}, \mathrm{C} 3=100 \mathrm{pF}$ and 220 pF Coupling capacitors at RFin and RFout.

